

# **UG30APT thru UG30DPT**

Vishay General Semiconductor

## **Dual Common-Cathode Ultrafast Plastic Rectifier**



PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub> 30 A						
V <sub>RRM</sub>	50 V to 200 V					
I <sub>FSM</sub>	300 A					
t <sub>rr</sub>	25 ns					
V <sub>F</sub>	0.85 V					
T <sub>J</sub> max.	150 °C					

### FEATURES

- Glass passivated chip junction
- Ultrafast recovery time
- Low switching losses, high efficiency
- Low forward voltage drop
- High forward surge capability
- Solder dip 260 °C, 40 s
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

### **TYPICAL APPLICATIONS**

For use in high frequency rectifier of switching mode power supplies, inverters, freewheeling diodes, dc-to-dc converters, and other power switching application.

#### **MECHANICAL DATA**

Case: TO-247AD (TO-3P)

Epoxy meets UL 94V-0 flammability rating

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)								
PARAMETER	SYMBOL	UG30APT	UG30BPT	UG30CPT	UG30DPT	UNIT		
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	50	100	150	200	V		
Maximum RMS voltage	V <sub>RMS</sub>	35	70	105	140	V		
Maximum DC blocking voltage	V <sub>DC</sub>	50	100	150	200	V		
Maximum average forward rectified current at $T_C = 120 \text{ °C}$	I <sub>F(AV)</sub>	30			Α			
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I <sub>FSM</sub>	300			A			
Operating and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	- 65 to + 150				°C		

ELECTRICAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)									
PARAMETER	TEST CONDI	TIONS	SYMBOL	UG30APT UG30BPT UG30CPT UG30DPT				UNIT	
Maximum instantaneous forward voltage per diode	15 A 30 A 10 A	T <sub>J</sub> = 100 °C	V <sub>F</sub>	1.0 1.15 0.85				V	
Maximum DC reverse current at rated DC blocking voltage per diode		T <sub>A</sub> = 25 °C T <sub>A</sub> = 100 °C	I <sub>R</sub>	15 800			μA		





COMPLIANT

For technical questions within your region, please contact one of the following: PDD-Americas@vishay.com, PDD-Asia@vishay.com, PDD-Europe@vishay.com

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<b>ELECTRICAL CHARACTERISTICS</b> ( $T_A = 25 \degree C$ unless otherwise noted)										
PARAMETER	TEST CONDI	TIONS	SYMBOL	UG30APT UG30BPT UG30CPT UG30DPT				UNIT		
Maximum reverse recovery time	$I_{\rm F} = 0.5 \text{ A}, I_{\rm R} = 1.0 \text{ A},$ $I_{\rm rr} = 0.25 \text{ A}$		t <sub>rr</sub>	25				ns		
Maximum reverse recovery time	$I_{F} = 15 \text{ A}, V_{R} = 30 \text{ V}, \\ dI/dt = 50 \text{ A}/\mu\text{s}, \\ I_{RR} = 10 \% I_{RM}$	T <sub>J</sub> = 25 °C T <sub>J</sub> = 100 °C	t <sub>rr</sub>	35 50				ns		
Maximum recovered stored charge	$I_{F} = 15 \text{ A}, V_{R} = 30 \text{ V}, \\ dI/dt = 50 \text{ A}/\mu\text{s}, \\ I_{RR} = 10 \% I_{RM}$	T <sub>J</sub> = 25 °C T <sub>J</sub> = 100 °C	Q <sub>rr</sub>	22 50				nC		
Typical junction capacitance	4.0 V, 1 MHz		CJ	70			pF			

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)							
SYMBOL	IBOL UG30APT UG30BPT UG30CPT UG30DPT UNI						
$R_{ ext{ heta}JC}$	2.0				°C/W		
S	YMBOL	YMBOL UG30APT	YMBOL UG30APT UG30BPT	YMBOL UG30APT UG30BPT UG30CPT	YMBOL UG30APT UG30BPT UG30CPT UG30DPT		

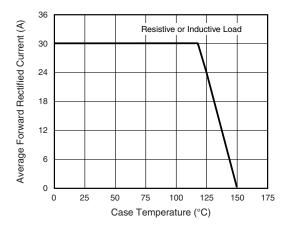
Note:

(1) Thermal resistance from junction to case per diode mounted on heatsink

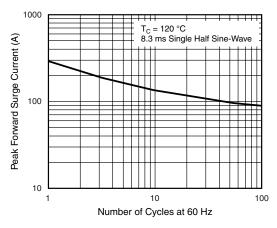
ORDERING INFORMATION (Example)								
PACKAGE	ACKAGE PREFERRED P/N UNIT WEIGHT (g) PACKAGE CODE BASE QUANTITY DELIVERY MODE							
TO-247AD	UG30DPT-E3/45	6.15	30	30/tube	Tube			

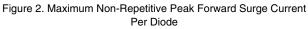
### **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)











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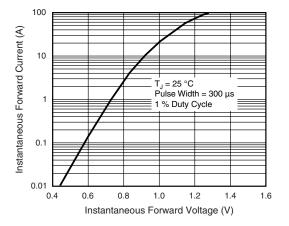


Figure 3. Typical Instantaneous Forward Characteristics Per Diode

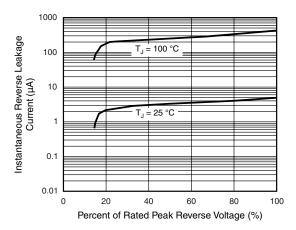


Figure 4. Typical Reverse Leakage Characteristics Per Diode

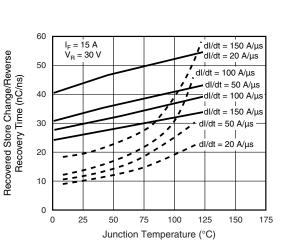


Figure 5. Reverse Switching Characteristics Per Diode

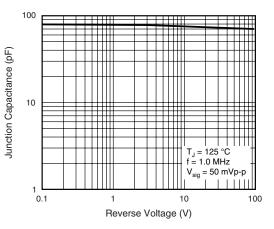
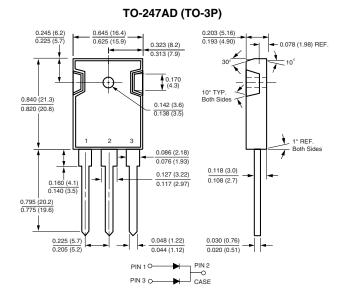


Figure 6. Typical Junction Capacitance Per Diode

#### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)





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